

## SILICON NPN POWER TRANSISITORS

... designed for medium-speed switching and amplifier applications

### FEATURES

- \* Gain Ranged Specified at 1A and 3A.
- \* Low  $V_{CE(sat)}$  : typically 0.5 V @  $I_C=5 A$ ,  $I_B=0.5A$
- \* Excellent Safe Operating Areas
- \* Complementary PNP Types Available 2N3789 thru 2N3792

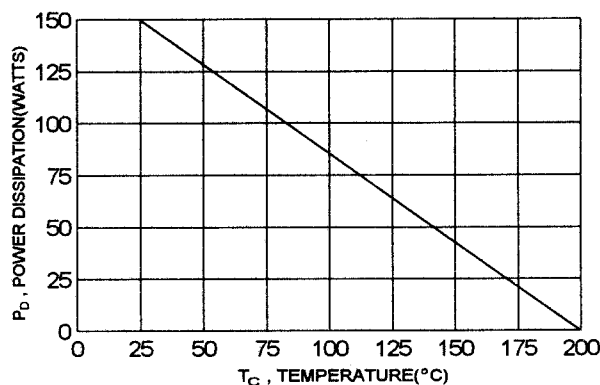
### MAXIMUM RATINGS

| Characteristic                                                          | Symbol         | 2N3713<br>2N3715 | 2N3714<br>2N3716 | Unit               |
|-------------------------------------------------------------------------|----------------|------------------|------------------|--------------------|
| Collector-Base Voltage                                                  | $V_{CBO}$      | 80               | 100              | V                  |
| Collector-Emitter Voltage                                               | $V_{CEO}$      | 60               | 80               | V                  |
| Emitter-Base Voltage                                                    | $V_{EBO}$      | 7                |                  | V                  |
| Collector Current - Continuous                                          | $I_C$          | 10               |                  | A                  |
| Base Current-Continuous                                                 | $I_B$          | 4                |                  | A                  |
| Total Power Dissipation @ $T_C=25^\circ C$<br>Derate above $25^\circ C$ | $P_D$          | 150<br>0.857     |                  | W<br>W/ $^\circ C$ |
| Operating and Storage Junction<br>Temperature Range                     | $T_J, T_{STG}$ | -65 to +200      |                  | $^\circ C$         |

### THERMAL CHARACTERISTICS

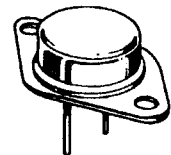
| Characteristic                      | Symbol          | Max  | Unit         |
|-------------------------------------|-----------------|------|--------------|
| Thermal Resistance Junction to Case | $R_{\theta jc}$ | 1.17 | $^\circ C/W$ |

FIGURE -1 POWER DERATING

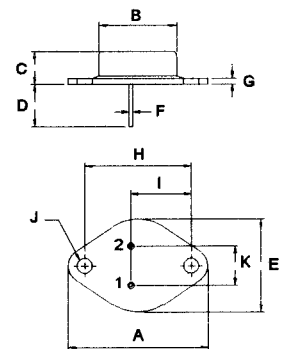


**NPN**  
**2N3713**  
**Thru**  
**2N3716**

**10 AMPERE**  
**POWER TRANSISTORS**  
**NPN SILICON**  
**60-80 VOLTS**  
**150 WATTS**



**TO-3**



PIN 1.BASE  
2.EMITTER  
COLLECTOR(CASE)

| DIM | MILLIMETERS |       |
|-----|-------------|-------|
|     | MIN         | MAX   |
| A   | 38.75       | 39.96 |
| B   | 19.28       | 22.23 |
| C   | 7.96        | 9.28  |
| D   | 11.18       | 12.19 |
| E   | 25.20       | 26.67 |
| F   | 0.92        | 1.09  |
| G   | 1.38        | 1.62  |
| H   | 29.90       | 30.40 |
| I   | 16.64       | 17.30 |
| J   | 3.88        | 4.36  |
| K   | 10.67       | 11.18 |

**ELECTRICAL CHARACTERISTICS** (  $T_c = 25^\circ\text{C}$  unless otherwise noted )

| Characteristic | Symbol | Min | Max | Unit |
|----------------|--------|-----|-----|------|
|----------------|--------|-----|-----|------|

**OFF CHARACTERISTICS**

|                                                                                                                                                                                                                                                                                                                                                    |                                                                      |               |                        |    |
|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|----------------------------------------------------------------------|---------------|------------------------|----|
| Collector-Emitter Sustaining Voltage (1)<br>( $I_C = 200\text{ mA}$ , $I_B = 0$ )                                                                                                                                                                                                                                                                  | 2N3713, 2N3715<br>2N3714, 2N3716                                     | $V_{CE(sus)}$ | 60<br>80               | V  |
| Collector -Emitter Cutoff Current<br>( $V_{CE} = 80\text{ V}$ , $V_{BE(off)} = -1.5\text{ V}$ )<br>( $V_{CE} = 100\text{ V}$ , $V_{BE(off)} = -1.5\text{ V}$ )<br>( $V_{CE} = 60\text{ V}$ , $V_{BE(off)} = -1.5\text{ V}$ , $T_c = 150^\circ\text{C}$ )<br>( $V_{CE} = 80\text{ V}$ , $V_{BE(off)} = -1.5\text{ V}$ , $T_c = 150^\circ\text{C}$ ) | 2N3713, 2N3715<br>2N3714, 2N3716<br>2N3713, 2N3715<br>2N3714, 2N3716 | $I_{CEX}$     | 1.0<br>1.0<br>10<br>10 | mA |
| Emitter Cutoff Current<br>( $V_{EB} = 7.0\text{ V}$ , $I_C = 0$ )                                                                                                                                                                                                                                                                                  | All Types                                                            | $I_{EBO}$     | 5.0                    | mA |

**ON CHARACTERISTICS (1)**

|                                                                                                                             |                                                                      |               |                      |            |   |
|-----------------------------------------------------------------------------------------------------------------------------|----------------------------------------------------------------------|---------------|----------------------|------------|---|
| DC Current Gain<br>( $I_C = 1.0\text{ A}$ , $V_{CE} = 2.0\text{ V}$ )<br>( $I_C = 3.0\text{ A}$ , $V_{CE} = 2.0\text{ V}$ ) | 2N3713, 2N3714<br>2N3715, 2N3716<br>2N3713, 2N3714<br>2N3715, 2N3716 | $h_{FE}$      | 25<br>50<br>15<br>30 | 90<br>180  |   |
| Collector-Emitter Saturation Voltage<br>( $I_C = 5.0\text{ A}$ , $I_B = 0.5\text{ A}$ )                                     | 2N3713, 2N3714<br>2N3715, 2N3716                                     | $V_{CE(sat)}$ |                      | 1.0<br>0.8 | V |
| Base-Emitter Saturation Voltage<br>( $I_C = 5.0\text{ A}$ , $I_B = 0.5\text{ A}$ )                                          | 2N3713, 2N3714<br>2N3715, 2N3716                                     | $V_{BE(sat)}$ |                      | 2.0<br>1.5 | V |
| Base-Emitter On Voltage<br>( $I_C = 3.0\text{ A}$ , $V_{CE} = 2.0\text{ V}$ )                                               | All Types                                                            | $V_{BE(on)}$  |                      | 1.5        | V |

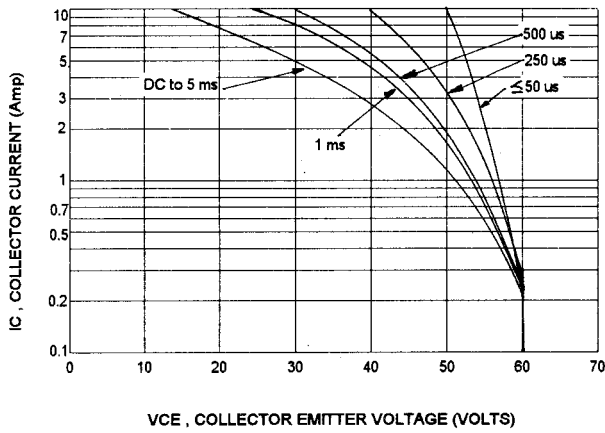
**DYNAMIC CHARACTERISTICS**

|                                                                                                           |       |     |  |     |
|-----------------------------------------------------------------------------------------------------------|-------|-----|--|-----|
| Current-Gain Bandwidth Product<br>( $I_C = 500\text{ mA}$ , $V_{CE} = 10\text{ V}$ , $f = 1\text{ MHz}$ ) | $f_T$ | 4.0 |  | MHz |
|-----------------------------------------------------------------------------------------------------------|-------|-----|--|-----|

(1) Pulse Test: Pulse width = 300  $\mu\text{s}$ , Duty Cycle  $\leq 2.0\%$ (2)  $f_T = |h_{fe}| \cdot f_{test}$

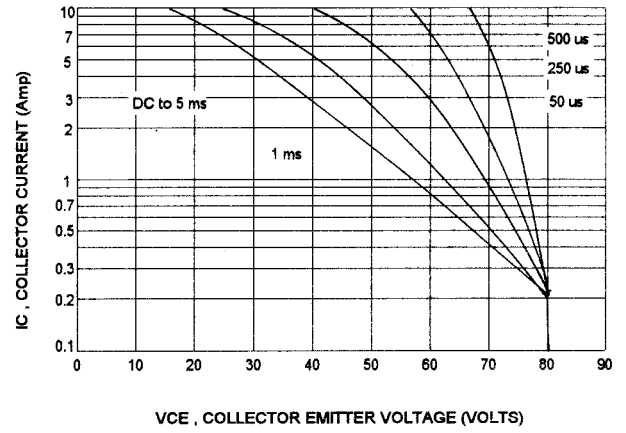
2N3713,2N3715

ACTIVE REGION SAFE OPERATING AREA

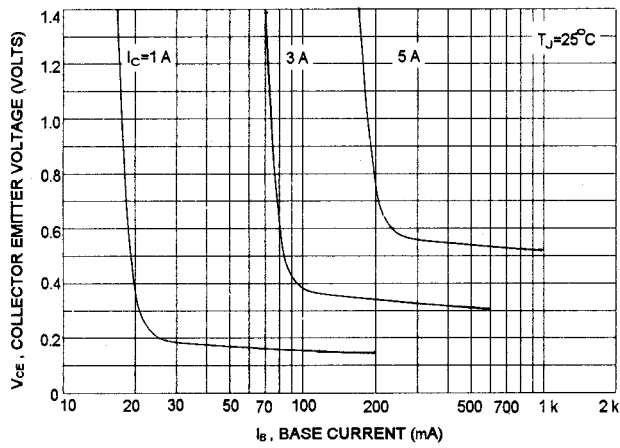


2N3714,2N3716

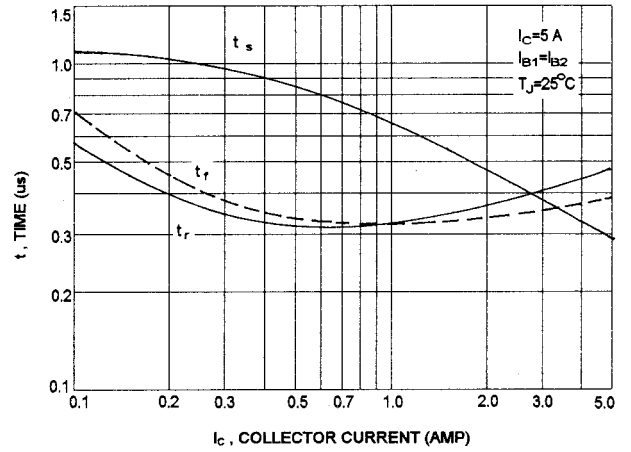
ACTIVE REGION SAFE OPERATING AREA



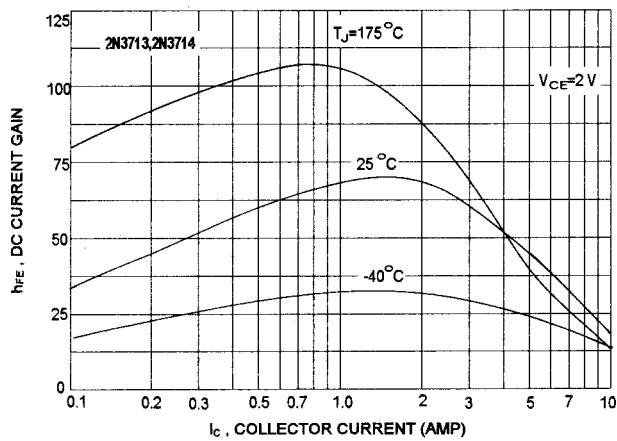
COLLECTOR SATURATION REGION



TYPICAL SWITCHING TIME



DC CURRENT GAIN



DC CURRENT GAIN

